

IGBT MODULE (N series)

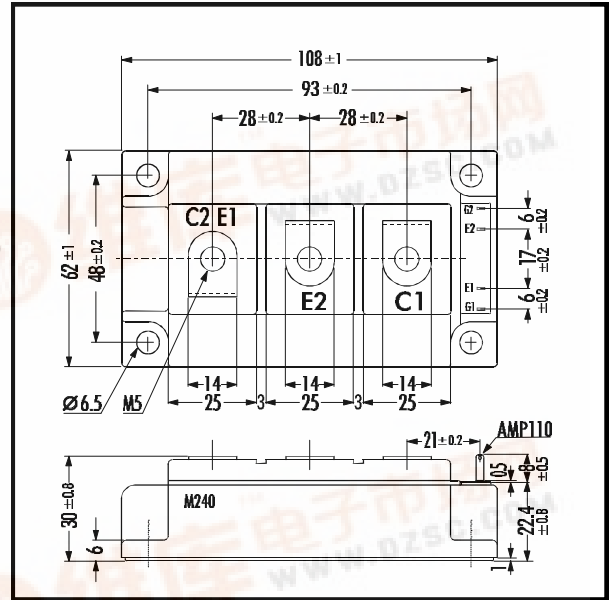
Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Improved FWD Characteristic
- Minimized Internal Stray Inductance
- Overcurrent Limiting Function (4-5 Times Rated Current)

Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

Outline Drawing



Maximum Ratings and Characteristics

Absolute Maximum Ratings (T_c=25°C)

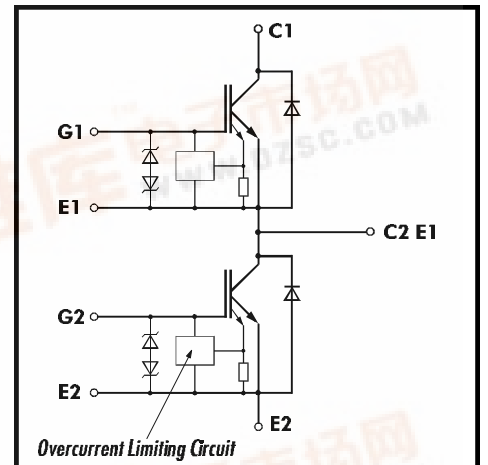
Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CE(S)}	1200	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	Continuous	I _C	150
	1ms	I _{C PULSE}	300
	Continuous	-I _C	150
	1ms	-I _{C PULSE}	300
Max. Power Dissipation	P _C	1100	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
Isolation Voltage	A.C. 1min.	V _{is}	2500
Screw Torque	Mounting *1	3.5	Nm
	Terminals *2	4.5	

Note: *1:Recommendable Value; 2.5 - 3.5 Nm (M5) or (M6)
*2:Recommendable Value; 3.5 - 4.5 Nm (M6)

Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CE(S)}	V _{GE} =0V V _{CE} =1200V			2.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			30	μA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =150mA	4.5		7.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =150A			3.3	V
Input capacitance	C _{ies}	V _{GE} =0V		24000		pF
Output capacitance	C _{oes}	V _{CE} =10V		8700		
Reverse Transfer capacitance	C _{res}	f=1MHz		7740		
Turn-on Time	t _{ON}	V _{CC} =600V		0.65	1.2	μs
	t _r	I _C =150A		0.25	0.6	
	t _{OFF}	V _{GE} =± 15V		0.85	1.5	
Turn-off Time	t _f	R _G =5.6Ω		0.35	0.5	μs
	t _{tr}					
Diode Forward On-Voltage	V _F	I _F =150A V _{GE} =0V			3.0	V
Reverse Recovery Time	t _{rr}	I _F =150A			350	ns

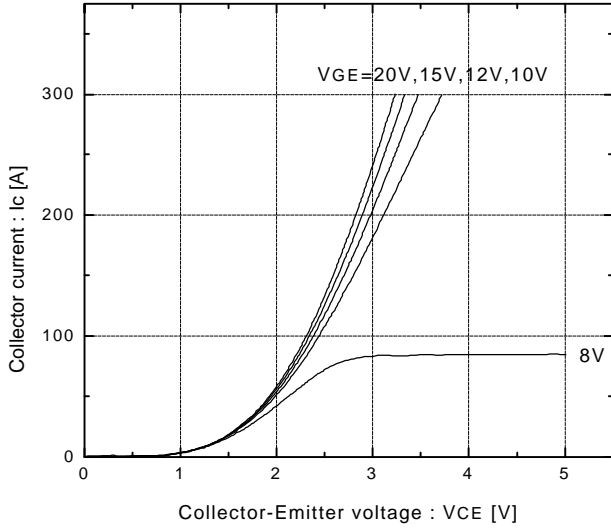
Equivalent Circuit



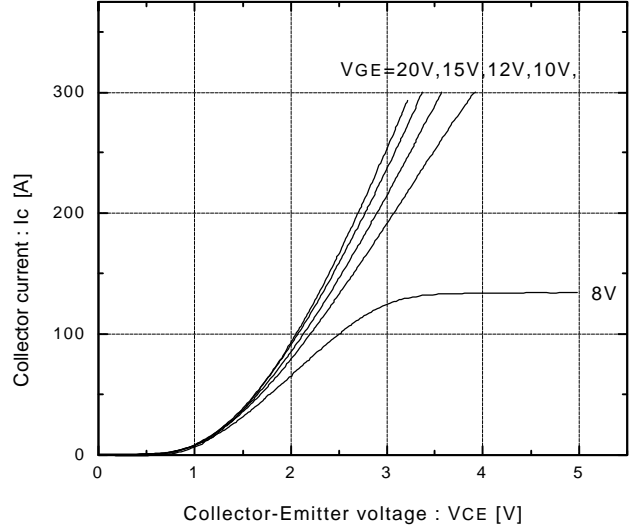
Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			0.11	°C/W
	R _{th(j-e)}	Diode			0.33	
	R _{th(c-f)}	With Thermal Compound		0.025		

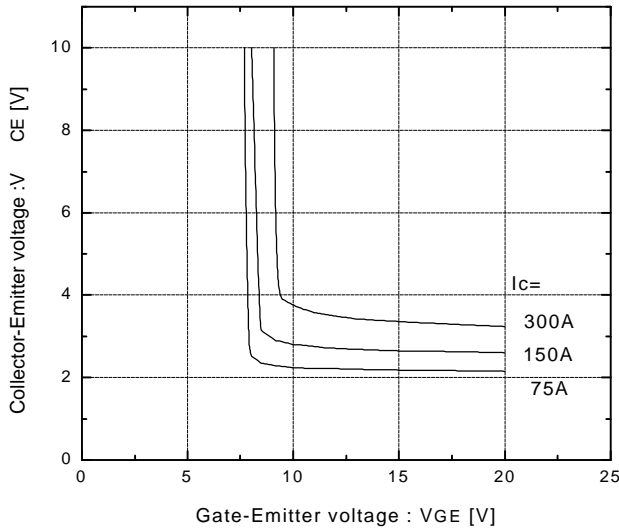
Collector current vs. Collector-Emitter voltage
T_j=25°C



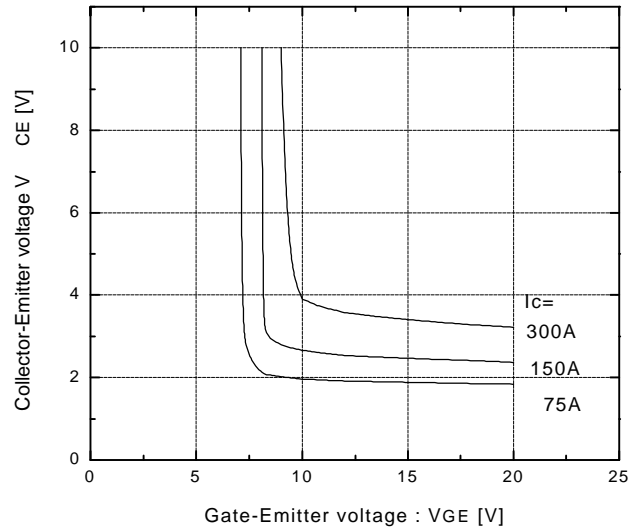
Collector current vs. Collector-Emitter voltage
T_j=125°C



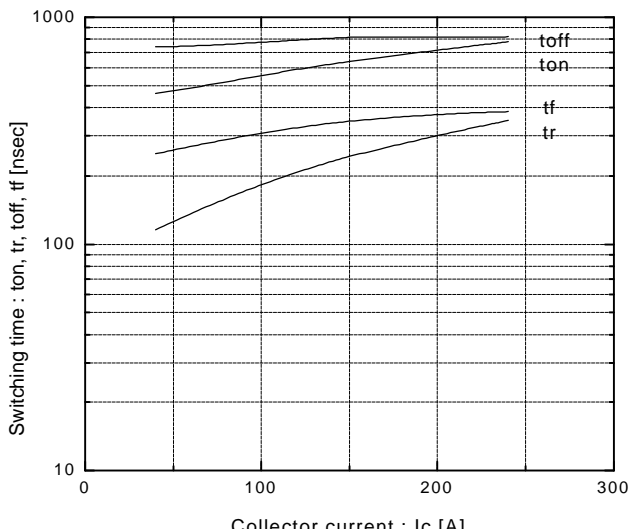
Collector-Emitter vs. Gate-Emitter voltage
T_j=25°C



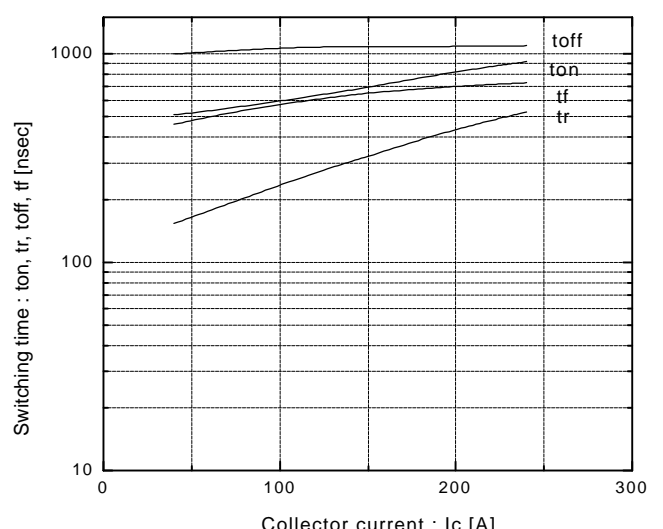
Collector-Emitter vs. Gate-Emitter voltage
T_j=125°C



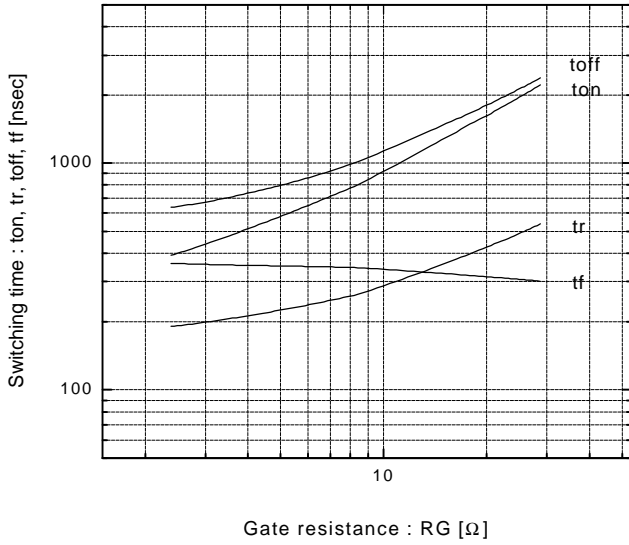
Switching time vs. Collector current
V_{cc}=600V, R_G=5.6Ω, V_{GE}=±15V, T_j=25°C



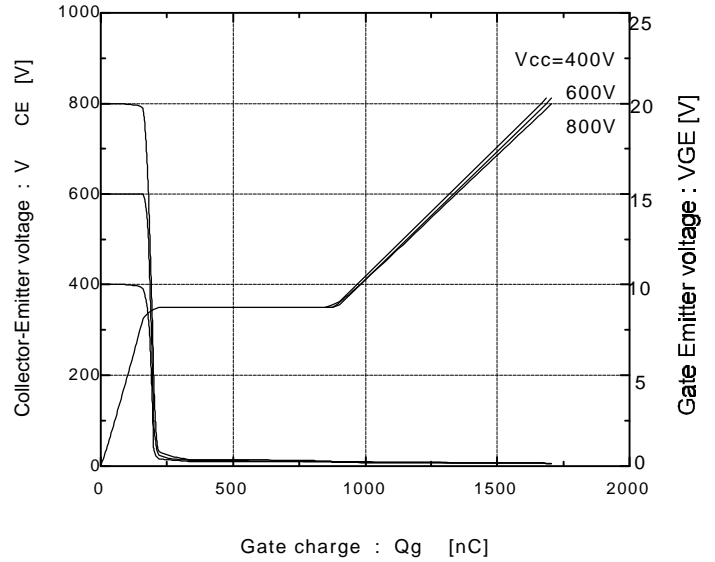
Switching time vs. Collector current
V_{cc}=600V, R_G=5.6Ω, V_{GE}=±15V, T_j=125°C



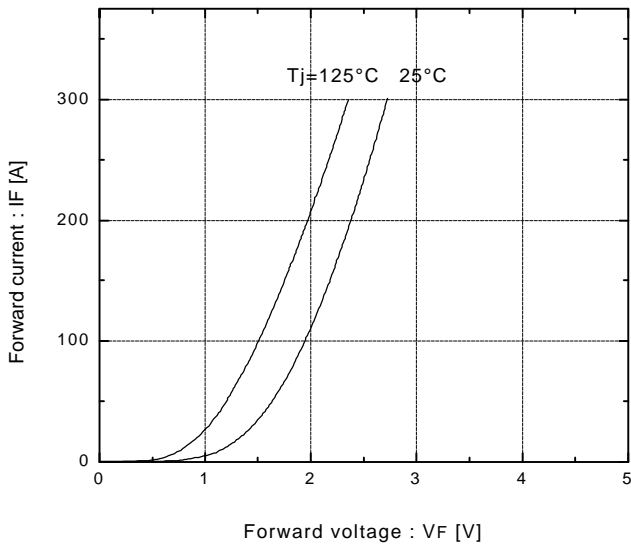
Switching time vs. R_G
 $V_{CC}=600V, I_C=150A, V_{GE}=\pm 15V, T_J=25^\circ C$



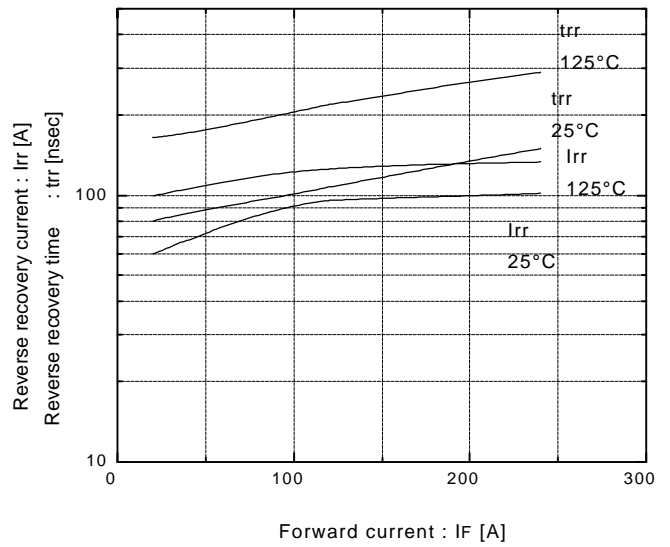
Dynamic input characteristics
 $T_J=25^\circ C$



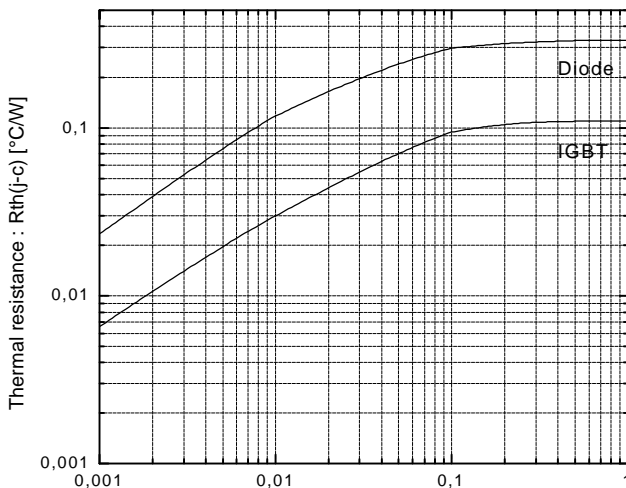
Forward current vs. Forward voltage
 $V_{GE}=0V$



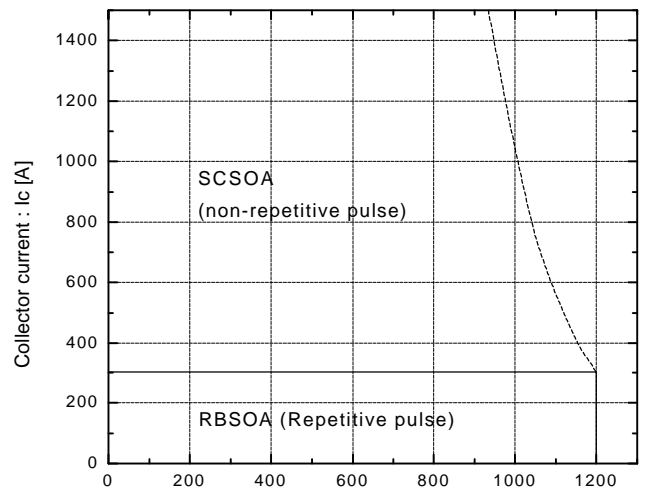
Reverse recovery characteristics
 t_{rr}, I_{rr} vs. I_F



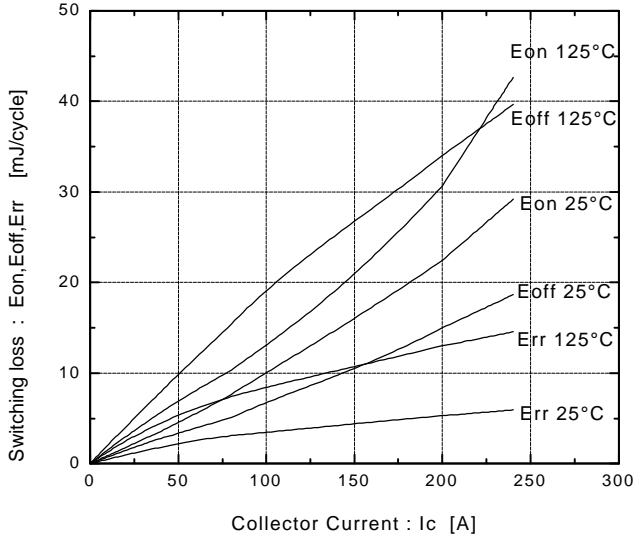
Transient thermal resistance



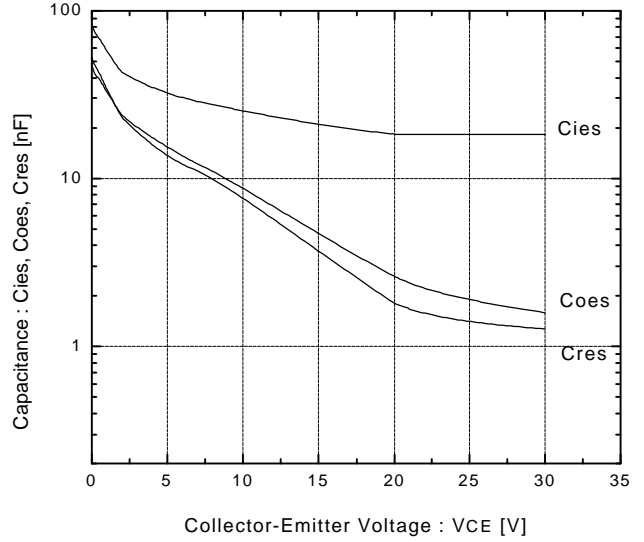
Reversed biased safe operating area
 $+V_{GE}=15V, -V_{GE}\leq 15V, T_J\leq 125^\circ C, R_G\geq 5.6\Omega$



Switching loss vs. Collector current
Vcc=600V, RG=5.6Ω, VGE=±15V



Capacitance vs. Collector-Emitter voltage
Tj=25°C



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